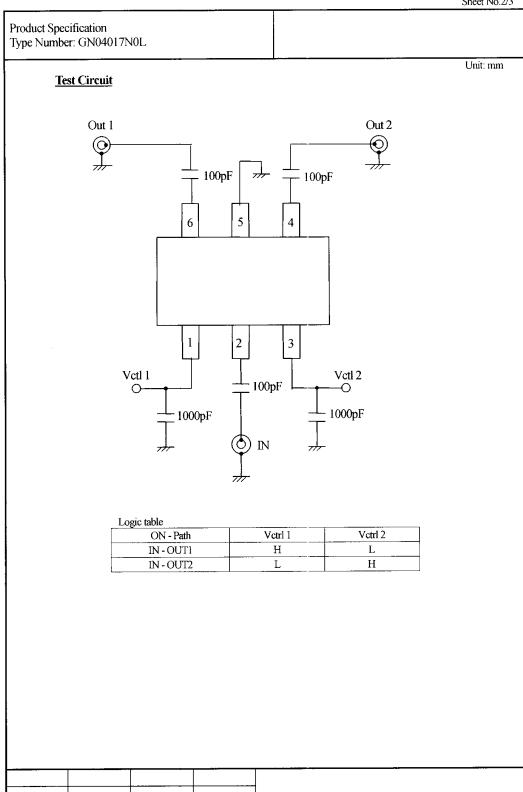
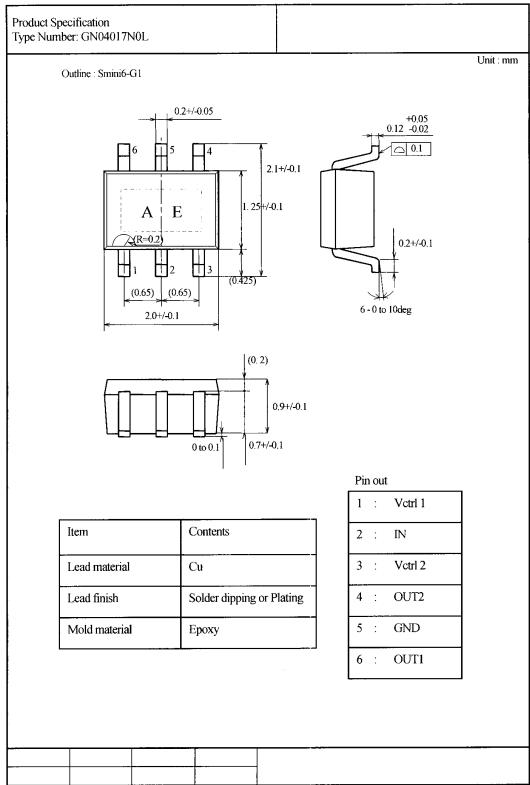
The state of the s			Designed Check		ed Checked		_	Approved	
Product Specification Type Number: GN04017N0L				Designed	CHECK	.cu	Checken	Арј	лочец
Туре	GaAs Integrated Circuit								
Application	High Frequency Switching for Mobile Communication								
Structure	N Channel Metal Semiconductor Type MMIC								
Outline	Smini6	-G1			Marking : AE				
Al-la Na-i		VDD	Vctrl(H)-Vctrl(L) Pin Topr +6 37 -30~+9			Tstg			
Absolute Maximum Ratings		8							
	(V) (V) (dBm) (degC) (degC) cs (Vcont(L)=0V, Vcont(H)=3.0V, f=1920 - 2170MHz, Ta=25+/-3degC)								
Electrical Characteristic	cs (Vcon	t(L)=0V, Vcor	nt(H)=3.0V, f=1920	<u>()</u>	Limit				
Item		Symbol *1 IL	Measuring Conditions			Тур.	Min	Max	Unit
Insertion Loss			IN-OUT1, Pin=26dBm, f=887~925MHz			0.20		0.45	dВ
			IN-OUT2, Pin=26dBm, f=887~925MHz			0.20		0.45	dΒ
Isolation Voltage Standing Wave Ratio		ISO *1 VSWR *2	IN-OUT1(IN-OUT2 ON) f=887~925MHz			28	23		dВ
			IN-OUT2(IN-OU	T1 ON) f=887~9	25MHz	28	23		dB
			IN-OUT1	f=887~9	25MHz	1.05		1.15	ďΒ
			IN-OUT2	f=887~9	25MHz	1.05		1.15	dΒ
Input 0.1dB Compression		Pin *1 (0.1dB)	Vctrl(H)=3V	f=887~9	925MHz	32	30		dBm
Input 1dB Compression		Pin *2 (1.0dB)	Vctrl(H)=3V	f=887~9	025MHz	34	32		dBm
Control Current		*1 Ictrl				10		30	uА
Switching Time		Tsw				0.2		1	us
Note: *1: See the test circuits *2: Designed specificat		xt page							

Semiconductor Company, Matsushita Electric Industrial Co., Ltd.



Semiconductor Company, Matsushita Electric Industrial Co., Ltd



Semiconductor Company, Matsushita Electric Industrial Co., Ltd.